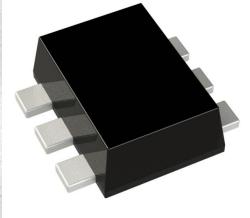


# DMG1024UV-7 Datasheet

www.digi-electronics.com

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DiGi Electronics Part Number	DMG1024UV-7-DG
Manufacturer	Diodes Incorporated
Aanufacturer Product Number	DMG1024UV-7
Description	MOSFET 2N-CH 20V 1.38A SOT563
Detailed Description	Mosfet Array 20V 1.38A 530mW Surface Mount SOT -563

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DMG1024UV-7	Diodes Incorporated
Series:	Product Status:
	Active
Technology:	Configuration:
MOSFET (Metal Oxide)	2 N-Channel (Dual)
FET Feature:	Drain to Source Voltage (Vdss):
Logic Level Gate	20V
Current - Continuous Drain (Id) @ 25°C:	Rds On (Max) @ ld, Vgs:
1.38A	450mOhm @ 600mA, 4.5V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
1V @ 250μΑ	0.74nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds:	Power - Max:
60.67pF @ 16V	530mW
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
SOT-563, SOT-666	SOT-563
Base Product Number:	
DMG1024	

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	



#### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

#### **Features**

- **Dual N-Channel MOSFET**
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- Lead Free By Design/RoHS Compliant (Note 1)
- ESD Protected Up To 2KV
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

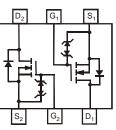
#### **Mechanical Data**

- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.006 grams (approximate)









TOP VIEW

TOP VIEW



#### **Maximum Ratings** $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic			Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	20	V		
Gate-Source Voltage			V <sub>GSS</sub>	±6	V
Continuous Drain Current (Note 3)	Steady State	T <sub>A</sub> = 25°C T <sub>A</sub> = 85°C	ID	1.38 0.89	А
Pulsed Drain Current (Note 4)			I <sub>DM</sub>	3	А

## **Thermal Characteristics**

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 3)	PD	530	mW
Thermal Resistance, Junction to Ambient $@T_A = 25^{\circ}C$ (Note 3)	R <sub>θJA</sub>	235	°C/W
Operating and Storage Temperature Range	TJ, T <sub>STG</sub>	-55 to +150	°C

1. No purposefully added lead. Notes:

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

3. Device mounted on FR-4 PCB, with minimum recommended pad layout.

4. Repetitive rating, pulse width limited by junction temperature.



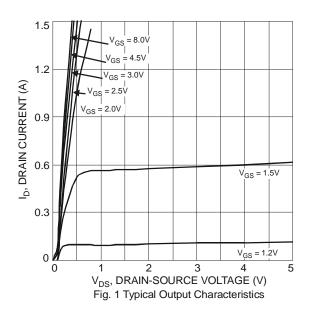
#### **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

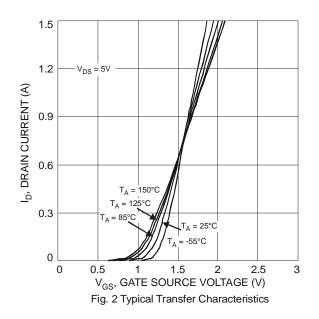
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = 25°C	I <sub>DSS</sub>	-	-	100	nA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±1.0	μA	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.5	-	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
			0.3	0.45		$V_{GS} = 4.5V, I_D = 600mA$
		-	0.4	0.6		$V_{GS} = 2.5V, I_D = 500mA$
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>		0.5	0.75	Ω	$V_{GS} = 1.8V, I_D = 350mA$
			-	9		$V_{GS} = 1.7V, I_D = 140mA$
			-	10		V <sub>GS</sub> = 1.5V, I <sub>D</sub> = 100mA
Forward Transfer Admittance	Y <sub>fs</sub>	-	1.4	-	S	$V_{DS} = 10V, I_D = 400mA$
Diode Forward Voltage	V <sub>SD</sub>		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 150mA$
DYNAMIC CHARACTERISTICS (Note 6)						
Input Capacitance	Ciss	-	60.67	-	pF	
Output Capacitance	C <sub>oss</sub>	-	9.68	-	pF	$V_{DS} = 16V, V_{GS} = 0V,$ - f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	-	5.37	-	pF	1 = 1.00012
Total Gate Charge	Qg	-	736.6	-	рС	
Gate-Source Charge	Q <sub>gs</sub>	-	93.6	-	рС	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q <sub>gd</sub>	-	116.6	-	рС	$I_D = 250 \text{mA}$
Turn-On Delay Time	t <sub>D(on)</sub>	-	5.1	-	ns	
Turn-On Rise Time	tr	-	7.4	-	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t <sub>D(off)</sub>	-	26.7	-	ns	$R_{L} = 47\Omega, R_{G} = 10\Omega,$ $I_{D} = 200 \text{mA}$
Turn-Off Fall Time	t <sub>f</sub>	-	12.3	-	ns	ID = 20011A

NEW PRODUCT

Notes: 5. Short duration pulse test used to minimize self-heating effect.

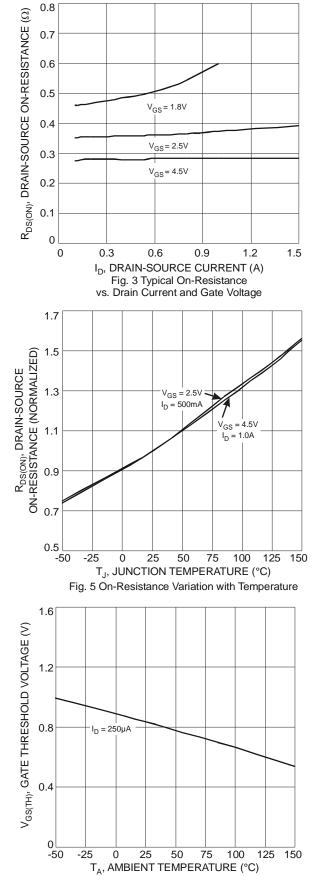
6. Guaranteed by design. Not subject to production testing.

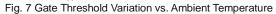






## DMG1024UV





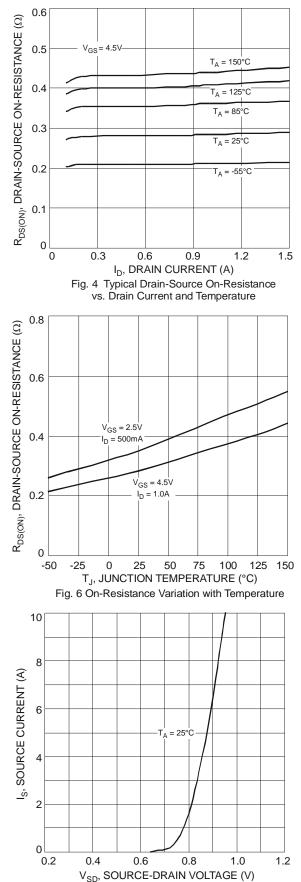
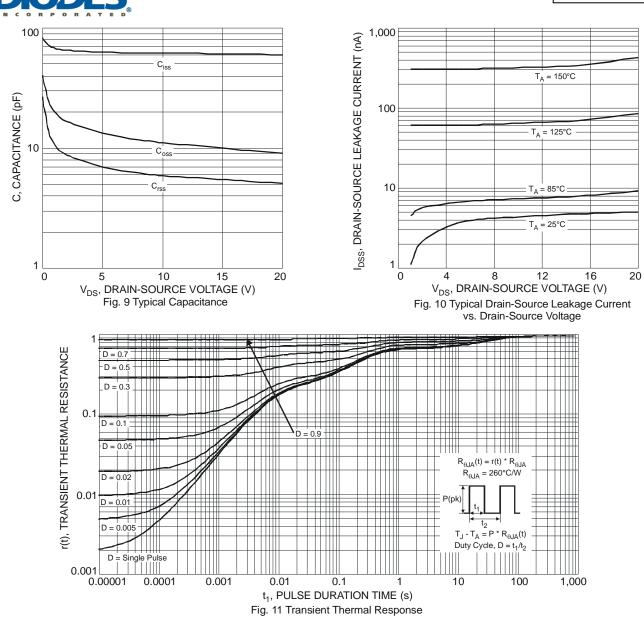


Fig. 8 Diode Forward Voltage vs. Current





## Ordering Information (Note 7)

Part Number	Case	Packaging
DMG1024UV-7	SOT-563	3000 / Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

#### **Marking Information**

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Т			ТТ	-

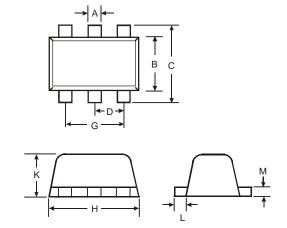
NA1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: W = 2009)

M = Month (ex: 9 = September)

Date Code Key						-					-	
Year	2009	9	2010		2011	20	12	2013		2014	2	2015
Code	W		Х		Y	2	7	А		В		С
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

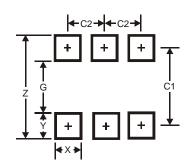


## Package Outline Dimensions



	SOT-563					
Dim	Min	Max	Тур			
Α	0.15	0.30	0.20			
В	1.10	1.25	1.20			
С	1.55	1.70	1.60			
D	-	-	0.50			
G	0.90	1.10	1.00			
Н	1.50	1.70	1.60			
Κ	0.55	0.60	0.60			
L	0.10	0.30	0.20			
Μ	0.10	0.18	0.11			
All	Dimens	sions in	mm			

# Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5



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